

RJH1CV7DPQ-E0

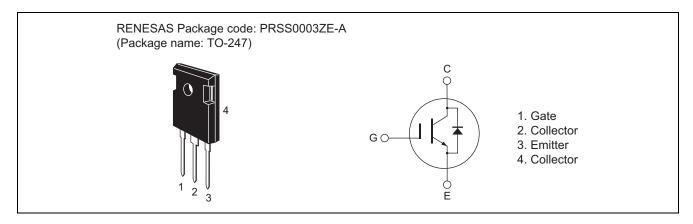
1200V - 35A - IGBT Application: Inverter

R07DS0525EJ0800 Rev.8.00 Nov 05, 2014

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8 \text{ V}$ typ. (at $I_C = 35 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 200 \text{ ns typ.}$) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 280 ns typ. (at V_{CC} = 600 V, V_{GE} = 15 V, I_C = 35 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	1200	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	70	А
	Tc = 100°C	Ic	35	А
Collector peak current		ic(peak) Note1	105	А
Collector to emitter diode forward current		I _{DF}	35	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	105	А
Collector dissipation		P _C Note2	320	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.39	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

 $di_F/dt = 100 A/\mu s$

 μC

Α

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current / Diode reverse current	I _{CES} /I _R	_	_	100	μА	V _{CE} = 1200 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.5	_	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_C = 35 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V _{CE(sat)}	_	2.5	_	V	$I_C = 70 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	2150	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	100	_	pF	$V_{GE} = 0$
Reverse transfer capacitance	Cres	_	55	_	pF	f = 1 MHz
Total gate charge	Qg	_	166	_	nC	V _{GE} = 15 V
Gate to emitter charge	Qge	_	20	_	nC	V _{CE} = 300 V
Gate to collector charge	Qgc	_	95	_	nC	I _C = 35 A
Turn-on delay time	t _{d(on)}	_	53	_	ns	$V_{CC} = 600 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 35 \text{ A}$ $Rg = 5 \Omega$ Inductive load
Rise time	t _r	_	45	_	ns	
Turn-off delay time	t _{d(off)}	_	185	_	ns	
Fall time	t _f	_	280	_	ns	
Turn-on energy	Eon	_	3.2	_	mJ	
Turn-off energy	E _{off}	_	2.5	_	mJ	
Total switching energy	E _{total}	_	5.7	_	mJ	
Short circuit withstand time	t _{sc}	_	5	_	μѕ	$V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$ $Tc \le 125^{\circ}C$
FRD forward voltage	V _F	_	2.1	l —	V	I _F = 35 A ^{Note3}
FRD reverse recovery time	t _{rr}	_	200	_	ns	I _F = 35 A
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0.7

9.6

 Q_{rr}

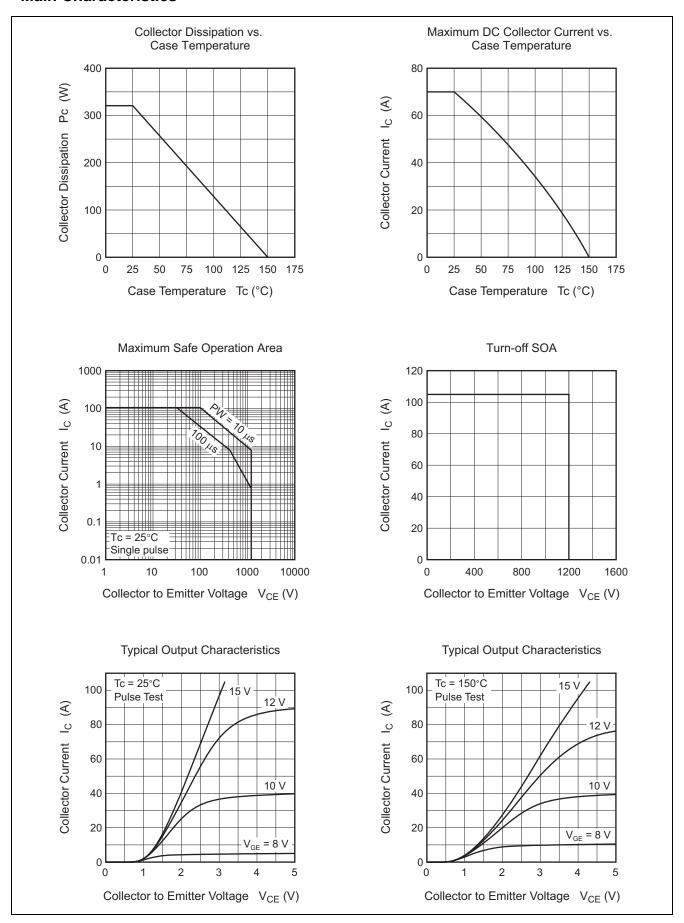
 I_{rr}

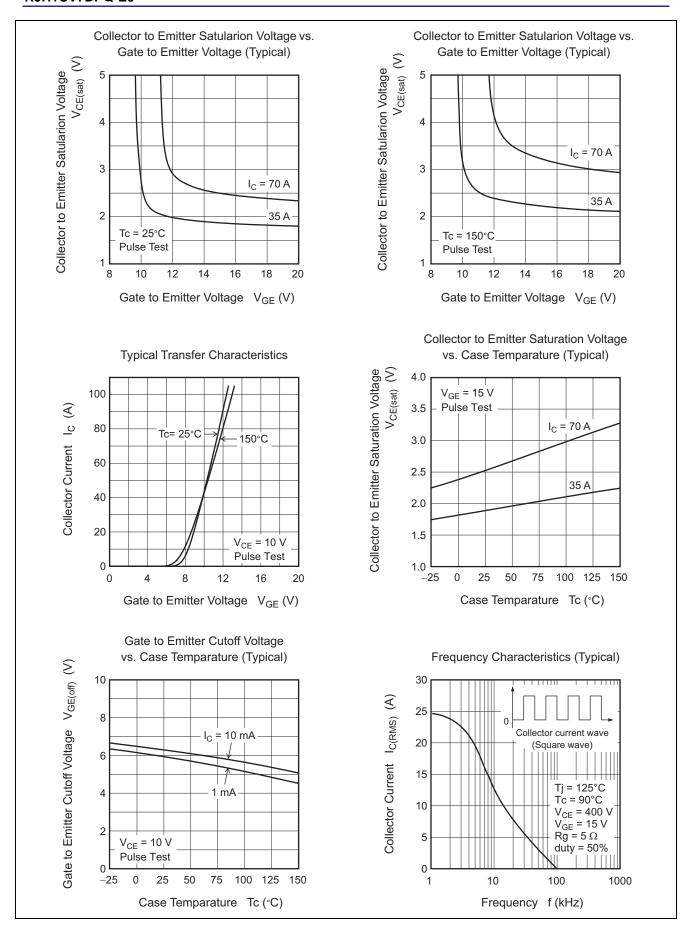
Notes: 3. Pulse test.

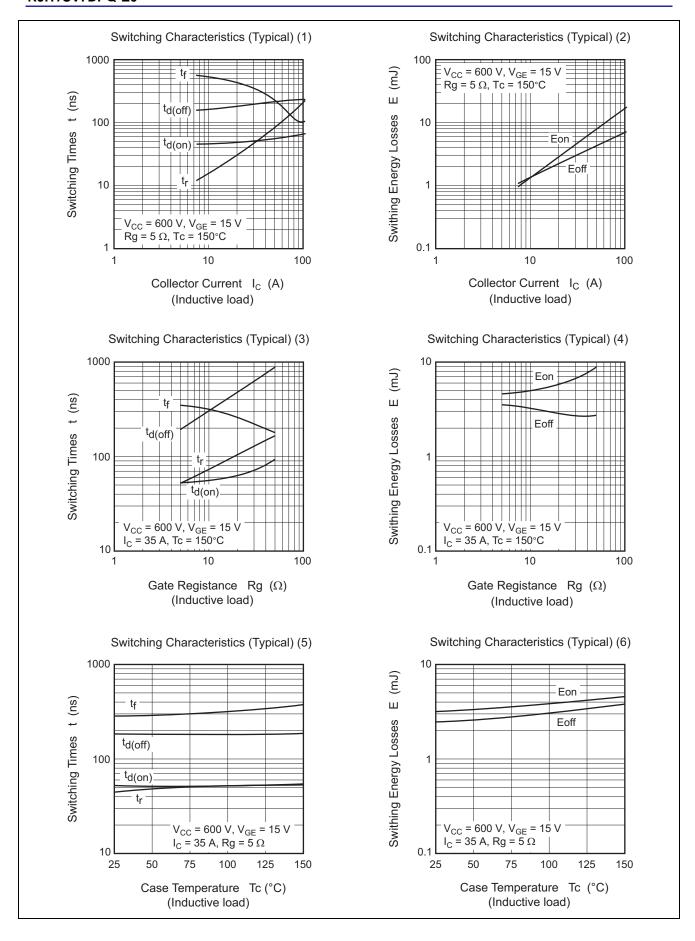
FRD reverse recovery charge

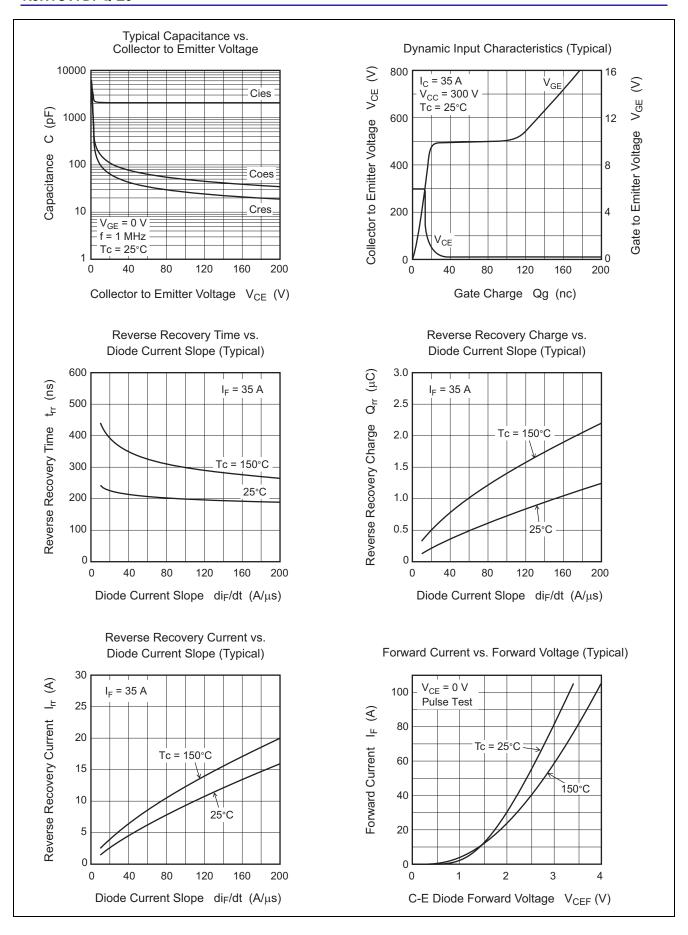
FRD peak reverse recovery current

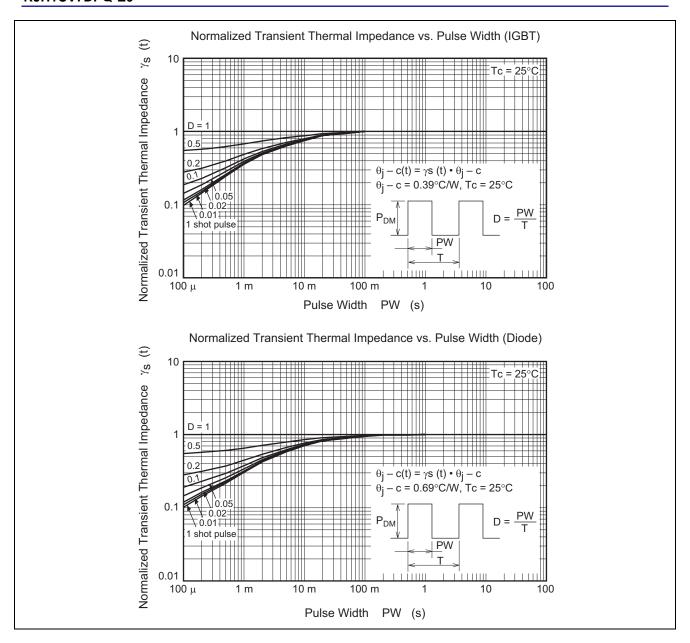
Main Characteristics

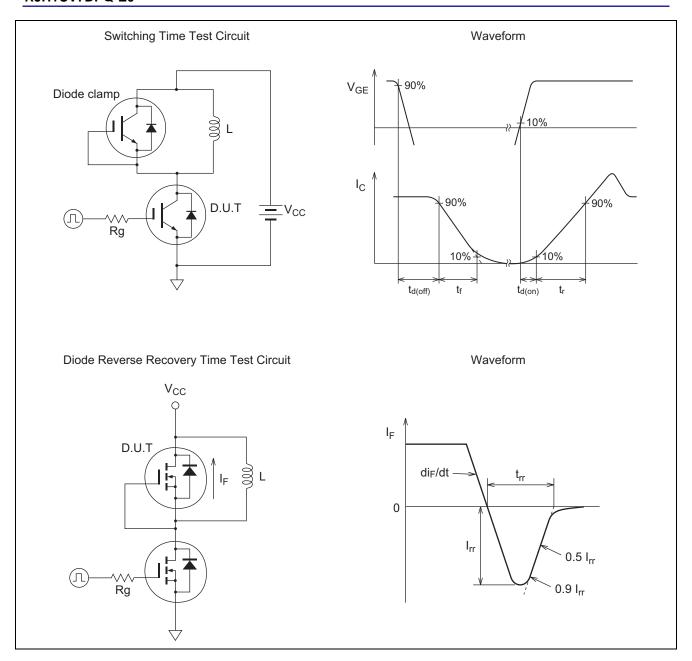




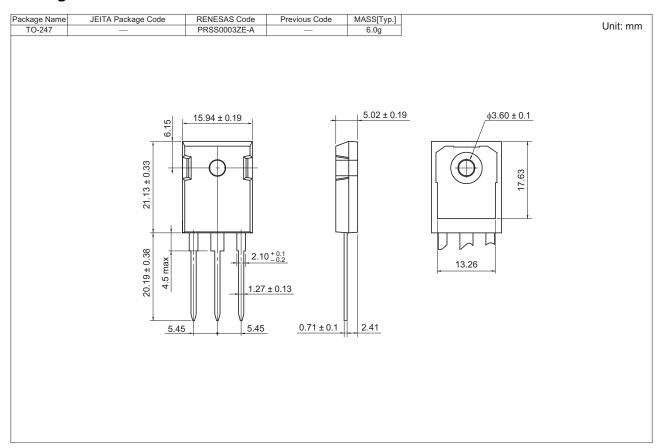








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJH1CV7DPQ-E0#T2	450 pcs	Tube	

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